

M/A-COM Products Released - Rev. 07.07

Designed primarily for wideband large—signal output and driver stages to 30 – 500 MHz.

N-Channel enhancement mode MOSFET

- Push–pull configuration reduces even numbered harmonics
- Guaranteed performance at 500 MHz, 28 Vdc

Output power = 40 W

Gain = 14 dB

Efficiency = 50%

Typical performance at 175 MHz, 28 Vdc

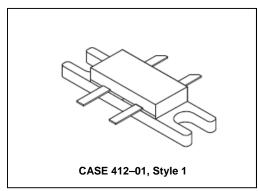
Output power = 40 W

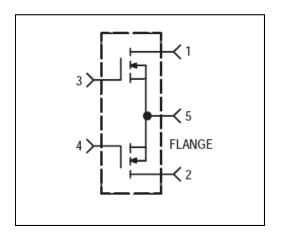
Gain = 17 dB

Efficiency = 60%

- Excellent thermal stability, ideally suited for Class A operation
- Facilitates manual gain control, ALC and modulation techniques
- 100% tested for load mismatch at all phase angles with 30:1 VSWR
- Low Crss 4.0 pF @ VDS = 28 V

Product Image





MAXIMUM RATINGS (T.j = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit	
Drain-Gate Voltage	VDSS	65	Vdc	
Drain-Gate Voltage (R _{GS} = 1.0 MΩ)	VDGR	65	Vdc	
Gate–Source Voltage	VGS	± 20	Adc	
Drain Current — Continuous	ΙD	8.0	ADC	
Total Device Dissipation @ T _C = 25°C Derate above 25°C	PD	175 1.0	Watts °C/W	
Storage Temperature Range	T _{stg}	-65 to +150	°C	
Operating Junction Temperature	TJ	200	°C	

THERMAL CHARACTERISTICS

Thermal Resistance — Junction to Case	$R_{\theta JC}$	1.0	°C/W

NOTE — <u>CAUTION</u> — MOS devices are susceptible to damage from electrostatic charge. Reasonable precautions in handling and packaging MOS devices should be observed.

- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macomtech.com for additional data sheets and product information.



The RF MOSFET Line 40W, 500MHz, 28V

M/A-COM Products Released - Rev. 07.07

ELECTRICAL CHARACTERISTICS (TC = 25°C unless otherwise noted)

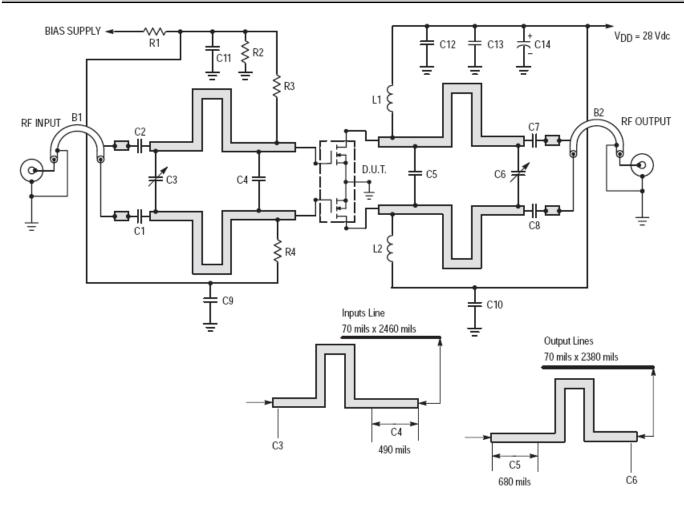
Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS (1)					
Drain–Source Breakdown Voltage (V _{GS} = 0 Vdc, I _D = 5.0 mA)	V(BR)DSS	65	_	_	Vdc
Zero Gate Voltage Drain Current (V _{DS} = 28 Vdc, V _{GS} = 0 Vdc)	IDSS	_	_	0.5	mA
Gate-Source Leakage Current (VGS = 20 Vdc, VDS = 0 Vdc)	lGSS	_	_	1.0	μА
ON CHARACTERISTICS (1)					
Gate Threshold Voltage (VDS= 10 Vdc, ID = 25 mA)	V _{GS(th)}	1.5	3.0	4.5	Vdc
Forward Transconductance (VDS= 10 Vdc, ID = 1.5 A)	9fs	0.9	1.1	_	mS
DYNAMIC CHARACTERISTICS (1)					•
Input Capacitance (VDS = 28 Vdc, VGS = 0 Vdc, f = 1.0 MHz)	C _{iss}	_	28	_	pF
Output Capacitance (VDS = 28 Vdc, VGS = 0 Vdc, f = 1.0 MHz)	C _{oss}	_	30	_	pF
Reverse Transfer Capacitance (VDS = 28 Vdc, VGS = 0 Vdc, f = 1.0 MHz)	C _{rss}	_	4.0	_	pF
FUNCTIONAL CHARACTERISTICS (2)					
Common Source Power Gain (V _{DD} = 28 Vdc, P _{out} = 40 W, f = 500 MHz, I _{DQ} = 100 mA)	G _{ps}	14	16	_	dB
Drain Efficiency (V _{DD} = 28 Vdc, P _{out} = 40 W, f = 500 MHz, I _{DQ} = 100 mA)	η	50	55	_	%
Electrical Ruggedness (VDD = 28 Vdc, Pout = 40 W, f = 500 MHz, IDQ = 100 mA) Load VSWR = 30:1, All phase angles at frequency of test	Ψ	No I	Degradation in	Output Pow	er
Series Equivalent Input Impedance (V _{DD} = 28 Vdc, P _{out} = 40 W, f = 500 MHz, I _{DQ} = 100 mA)	Z _{in}	_	2.88 –j7.96	_	Ohms
Series Equivalent Output Impedance (VDD = 28 Vdc, P _{out} = 40 W, f = 500 MHz, I _{DQ} = 100 mA)	Z _{out}	_	6.12 –j9.43	_	Ohms

⁽¹⁾ Each transistor chip measured separately.

⁽²⁾ Both transistor chips operating in a push-pull amplifier.



M/A-COM Products Released - Rev. 07.07



C1, C2, C7, C8 220 pF, 100 mil Chip Capacitor, ATC

C3, C6 0 - 10 pF, Johanson

C4 27 pF, 100 mil Chip Capacitor, ATC 22 pF, 100 mil Chip Capacitor, ATC C5

C9, C10, C11, C12 0.01 µF Blue Capacitor

C13 470 pF, 100 mil Chip Capacitor, ATC C14 50 μF, 50 V Electrolytic Capacitor L1. L2 8 Turns #20 AWG, 0.100 mils ID

B1, B2 6" long, ID = 550 mils, 50 Ω Semi-Rigid Coax

R1 1.0 kΩ 1/2 Watt 10 kΩ 1/2 Watt R2 R3. R4 45 Ω 1/2 Watt Board Material - Teflon® Fiberglass

Dielectric Thickness = 0.30", ε_r = 2.55 Copper Clad, 2.0 oz. Copper

Figure 1. MRF166W 500 MHz Test Circuit Schematic

ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions

[•] North America Tel: 800.366.2266 / Fax: 978.366.2266

Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298 Visit www.macomtech.com for additional data sheets and product information.



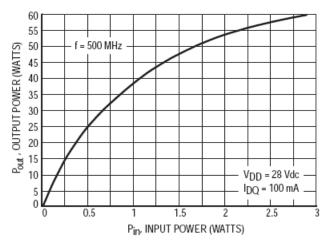


Figure 2. Output Power versus Input Power, 28 Vdc

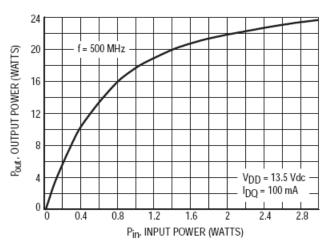


Figure 3. Output Power versus Input Power, 13.5 Vdc

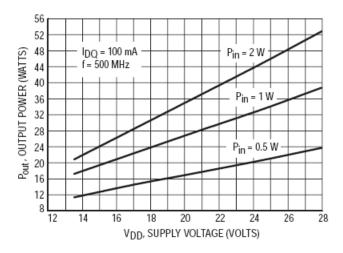


Figure 4. Output Power versus Supply Voltage

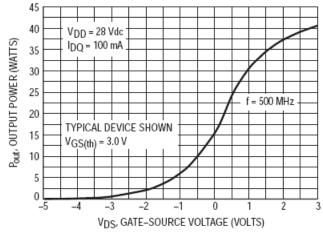


Figure 5. Output Power versus Gate Voltage

[•] **Europe** Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
Visit www.macomtech.com for additional data sheets and product information.



M/A-COM Products Released - Rev. 07.07

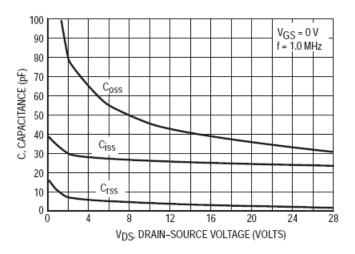
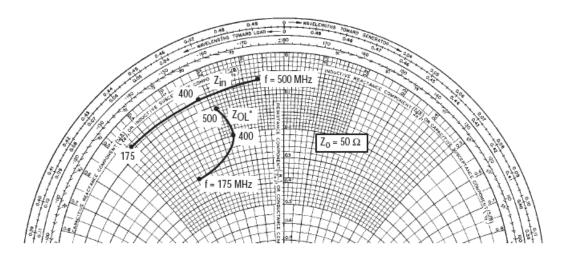


Figure 6. Capacitance versus Voltage



V_{DD} = 28 Vdc, I_{DO} = 100 mA, P_{out} = 40 W

f MHz	Z _{in} Ohms	Z _{OL} * Ohms
175	3.7 – j 22.4	15.2 – j 16.6
400	3.6 – j 10.99	10.3 – j 7.99
500	2.88 – j 7.96	6.12 – j 9.43

Table 1. Input and Output Impedances

ZOL* = Conjugate of the optimum load impedance into which the device output operates at a given output power, voltage and frequency.

NOTE: Input and output impedance values given are measured from gate to gate and drain to drain respectively.

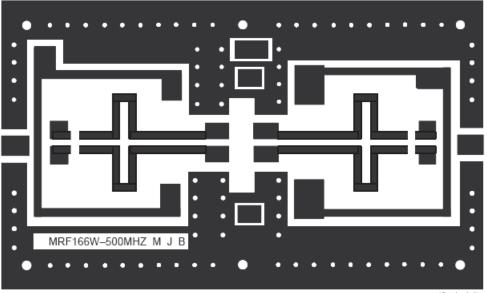
Figure 7. Series Equivalent Input/Output Impedance

PRELIMINARY: Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298 Visit www.macomtech.com for additional data sheets and product information.



M/A-COM Products Released - Rev. 07.07



NOTES: 1) 3 X 5 inch Glass Teflon® 32 Mil Board, Copper Both Sides (Scale 1:1)

- 2) Small Holes are 40 Mils ID and Plated Through
- 3) Large Holes are 140 Mils ID and Plated Through

Figure 8. MRF166W Circuit Board Photomaster

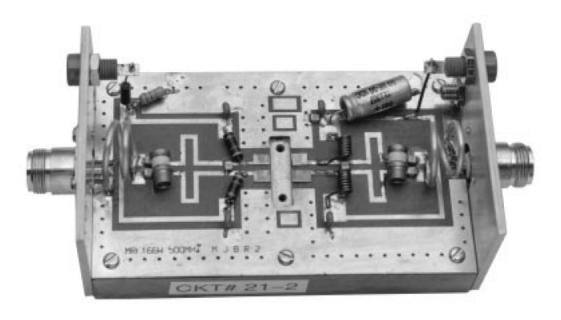


Figure 9. MRF166W Test Fixture

[•] Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macomtech.com for additional data sheets and product information.



Table 1. Common Source S-Parameters (VDS = 24 V, ID = 230 mA)

f	s	11	S	21	S	12	S	22
MHz	S ₁₁	ф	S ₂₁	ф	S ₁₂	ф	\$ ₂₂	ф
30	0.554	-85	20.30	128	0.044	28	0.628	-121
40	0.775	-113	20.00	113	0.040	26	0.632	-123
50	0.758	-124	17.50	107	0.041	20	0.652	-135
60	0.711	-132	14.60	100	0.050	20	0.570	-135
70	0.751	-139	12.70	100	0.042	11	0.666	-145
80	0.742	-143	11.30	95	0.043	9	0.666	-149
90	0.724	-146	10.00	92	0.042	8	0.657	-151
100	0.730	-149	8.97	90	0.042	6	0.663	-154
110	0.735	-151	8.29	87	0.043	3	0.683	-156
120	0.732	-153	7.53	84	0.042	2	0.666	-158
130	0.734	-155	7.01	83	0.042	1	0.688	-159
140	0.740	-156	6.57	81	0.043	0	0.701	-160
150	0.747	-157	6.01	78	0.042	-2	0.688	-162
160	0.748	-159	5.66	76	0.041	-4	0.715	-162
170	0.741	-160	5.22	76	0.040	-4	0.690	-161
180	0.746	-160	4.94	74	0.041	-4	0.719	-164
190	0.753	-161	4.67	73	0.041	-6	0.725	-165
200	0.756	-162	4.51	70	0.040	-7	0.729	-166
210	0.755	-162	4.15	69	0.039	-8	0.727	-165
220	0.759	-163	3.91	68	0.039	-8	0.724	-166
230	0.767	-163	3.75	65	0.039	-10	0.751	-169
240	0.769	-164	3.56	64	0.038	-12	0.733	-167
250	0.766	-164	3.41	63	0.037	-12	0.726	-167
260	0.767	-165	3.26	63	0.035	-10	0.725	-167
270	0.773	-165	3.07	61	0.035	-10	0.725	-167
280	0.777	-165	3.03	61	0.035	-11	0.753	-167
290	0.777	-166	2.89	58	0.034	-13	0.732	-169
300	0.782	-166	2.80	57	0.034	-11	0.744	-169
310	0.788	-166	2.66	57	0.034	-12	0.764	-169
320	0.794	-167	2.54	55	0.033	-12	0.760	-167
330	0.796	-167	2.47	54	0.032	-13	0.787	-169
340	0.795	-168	2.38	54	0.031	-13	0.753	-170
350	0.799	-168	2.27	52	0.030	-11	0.772	-168
360	0.804	-168	2.17	51	0.030	-11	0.782	-169
370	0.805	-168	2.15	50	0.030	-11	0.796	-169
380	0.807	-169	2.06	48	0.029	-12	0.782	-170
390	0.812	-169	2.00	48	0.028	-12	0.796	-170
400	0.818	-170	1.91	47	0.027	-10	0.784	-168
410	0.821	-170	1.86	46	0.029	-11	0.830	-170
420	0.821	-170	1.83	44	0.028	-11	0.823	-171
430	0.822	-171	1.74	44	0.026	-9	0.791	-170
440	0.826	-171	1.67	43	0.025	-7	0.788	-170

[•] North America Tel: 800.366.2266 / Fax: 978.366.2266

[•] Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macomtech.com for additional data sheets and product information.



The RF MOSFET Line 40W, 500MHz, 28V

Table 1. Common Source S-Parameters (VDS = 24 V, ID = 230 mA) (continued)

f	s ₁₁		s ₂₁		S.	s ₁₂		22
MHz	\$ ₁₁	ф	\$ ₂₁	ф	\$ ₁₂	ф	\$ ₂₂	ф
450	0.830	-171	1.68	42	0.025	-7	0.820	-170
460	0.831	-172	1.64	41	0.026	-10	0.843	-174
470	0.832	-172	1.54	41	0.025	-7	0.827	-173
480	0.835	-173	1.50	39	0.024	-3	0.836	-172
490	0.835	-173	1.43	38	0.024	1	0.835	-171
500	0.823	-174	1.43	37	0.025	3	0.849	-172
600	0.874	-176	1.12	29	0.003	-171	0.873	-176
700	0.910	-179	0.86	23	0.013	89	0.867	-177
800	0.932	179	0.74	18	0.035	61	0.904	178
900	0.966	176	0.63	12	0.029	68	0.897	179
1000	0.975	172	0.54	5	0.042	49	0.953	174

[•] Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macomtech.com for additional data sheets and product information.



The RF MOSFET Line 40W, 500MHz, 28V

Table 2. Common Source S-Parameters (VDS = 28 V, ID = 250 mA)

f	S	11	S	21	S-	12	S	22
MHz	S ₁₁	ф	\$ ₂₁	ф	S ₁₂	ф	S ₂₂	ф
30	0.601	-86	22.20	128	0.040	29	0.796	-119
40	0.783	-112	21.20	114	0.037	27	0.616	-122
50	0.764	-122	18.50	108	0.038	21	0.637	-133
60	0.727	-131	15.50	101	0.045	21	0.574	-135
70	0.759	-138	13.50	100	0.039	12	0.648	-143
80	0.751	-142	12.10	95	0.040	9	0.649	-148
90	0.732	-146	10.70	93	0.040	8	0.641	-150
100	0.737	-149	9.55	90	0.040	6	0.648	-153
110	0.741	-150	8.81	88	0.040	4	0.670	-155
120	0.738	-153	8.01	85	0.040	3	0.654	-156
130	0.740	-154	7.47	83	0.040	2	0.675	-157
140	0.747	-156	7.01	82	0.040	1	0.684	-158
150	0.754	-157	6.43	79	0.040	-2	0.669	-161
160	0.757	-159	6.07	77	0.039	-3	0.693	-161
170	0.749	-159	5.59	76	0.038	-3	0.670	-161
180	0.753	-160	5.28	75	0.039	-4	0.701	-163
190	0.759	-161	4.99	73	0.039	- 5	0.712	-164
200	0.761	-161	4.81	70	0.038	-7	0.719	-165
210	0.759	-162	4.44	70	0.037	-6	0.713	-163
220	0.762	-163	4.18	69	0.037	-7	0.709	-164
230	0.771	-164	4.03	66	0.037	-9	0.733	-167
240	0.775	-164	3.83	65	0.036	-10	0.715	-165
250	0.774	-165	3.69	64	0.035	-10	0.713	-166
260	0.775	-165	3.52	63	0.034	-10	0.715	-168
270	0.780	-165	3.29	61	0.034	-10	0.712	-168
280	0.782	-165	3.24	61	0.034	-11	0.741	-168
290	0.781	-166	3.10	59	0.032	-12	0.722	-168
300	0.785	-166	3.01	58	0.033	-11	0.733	-168

[•] Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macomtech.com for additional data sheets and product information.



The RF MOSFET Line 40W, 500MHz, 28V

Table 2. Common Source S-Parameters (VDS = 28 V, ID = 250 mA) (continued)

f S ₁₁		s ₂₁		s	s ₁₂		s ₂₂		
MHz	S ₁₁	ф	\$ ₂₁	ф	S ₁₂	ф	S ₂₂	ф	
310	0.792	-167	2.87	57	0.032	-12	0.750	-167	
320	0.798	-167	2.75	56	0.032	-12	0.739	-166	
330	0.801	-168	2.68	53	0.031	-13	0.760	-170	
340	0.800	-168	2.58	53	0.030	-14	0.727	-172	
350	0.803	-169	2.44	52	0.029	-12	0.755	-170	
360	0.807	-169	2.33	50	0.029	-12	0.772	-171	
370	0.808	-169	2.30	50	0.029	-12	0.787	-169	
380	0.809	-169	2.19	48	0.028	-13	0.768	-170	
390	0.813	-170	2.14	49	0.027	-13	0.775	-169	
400	0.820	-170	2.06	47	0.026	-11	0.765	-167	
410	0.823	-170	2.02	45	0.027	-12	0.805	-170	
420	0.823	-171	1.98	44	0.026	-13	0.794	-173	
430	0.824	-171	1.89	44	0.025	-12	0.778	-174	
440	0.828	-172	1.83	43	0.024	-11	0.785	-173	
450	0.832	-172	1.81	41	0.024	-10	0.812	-172	
460	0.833	-172	1.75	41	0.025	-13	0.838	-175	
470	0.835	-172	1.65	41	0.023	-11	0.817	-173	
480	0.840	-172	1.60	40	0.022	-10	0.818	-172	
490	0.844	-173	1.55	38	0.022	-10	0.819	-172	
500	0.845	-173	1.56	37	0.022	-10	0.833	-173	
600	0.879	-176	1.21	29	0.002	138	0.870	-176	
700	0.912	-179	0.92	23	0.017	77	0.862	-176	
800	0.935	179	0.79	18	0.039	58	0.887	179	
900	0.966	176	0.67	11	0.030	69	0.892	179	
1000	0.974	172	0.57	5	0.043	49	0.945	175	

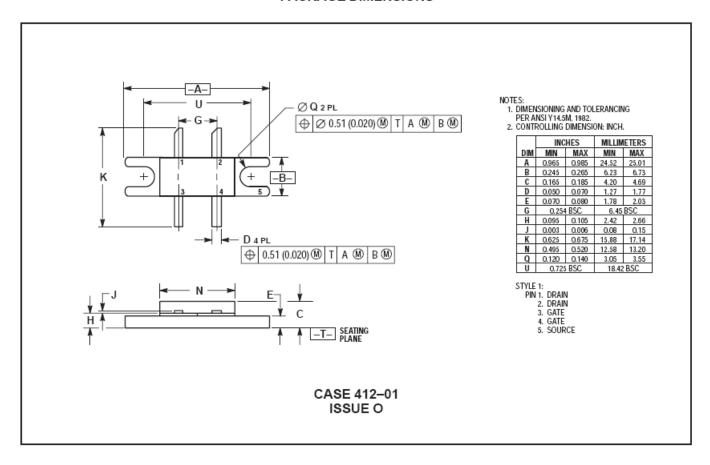
[•] Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macomtech.com for additional data sheets and product information.



M/A-COM Products Released - Rev. 07.07

PACKAGE DIMENSIONS



- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macomtech.com for additional data sheets and product information.